

**DESCRIPTION**

2SK492 is a super mini outline resin sealed silicon N channel junction type FET. It is designed for low frequency voltage amplify,application and analog switch application.

**FEATURE**

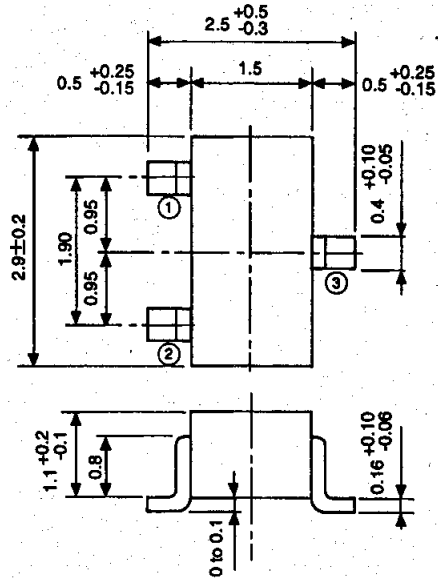
- Small type for mounting
- High  $|y_{fs}|$   $|y_{fs}|=8\text{mS}(\text{typ})$
- Low  $R_{DS(ON)}$   $R_{DS(ON)}=70\Omega$  typ

**APPLICATION**

General purpose voltage amplify,analog switch circuit for stereo,cassette deck,VCR.

**OUTLINE DRAWING**

Unit:mm



**TERMINAL CONNECTOR**

- ① : SOURCE
- ② : DRAIN
- ③ : GATE

EIAJ : SC-59

JEDEC : TO-236 resemblance

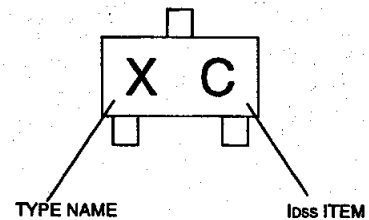
Note)

The dimension without tolerance represent central value.

**MAXIMUM RATINGS (Ta=25°C)**

Symbol	Parameter	Ratings	Unit
V <sub>GD0</sub>	Gate to Drain voltage	-50	V
I <sub>G</sub>	Gate current	10	mA
P <sub>T</sub>	Total allowable dissipation(Ta=25°C)	150	mW
T <sub>ch</sub>	Channel temperature	+125	°C
T <sub>stg</sub>	Storage temperature	-55 to +125	°C

**MARKING**



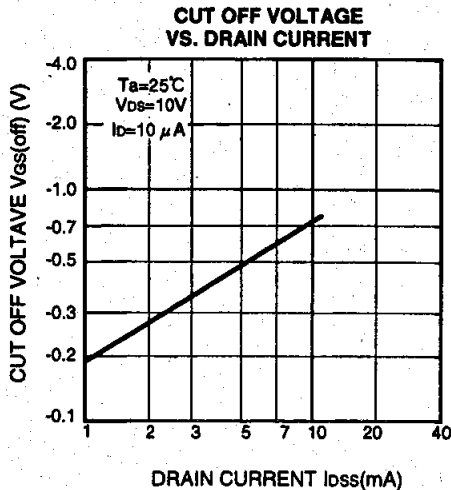
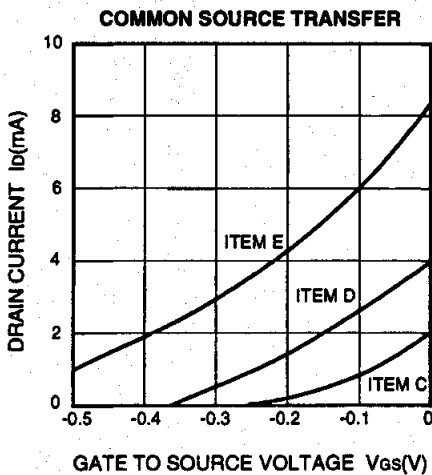
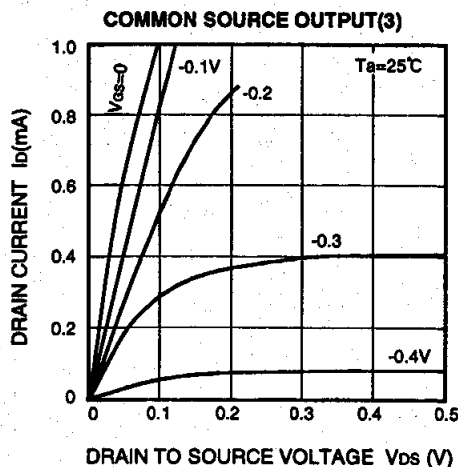
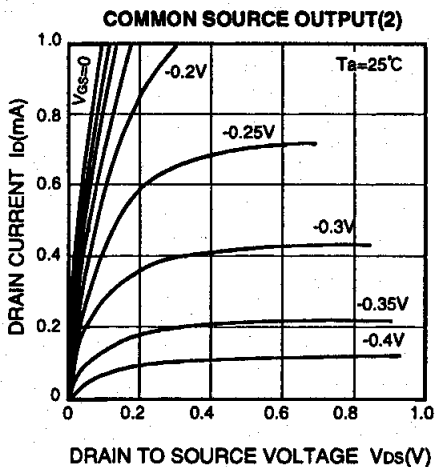
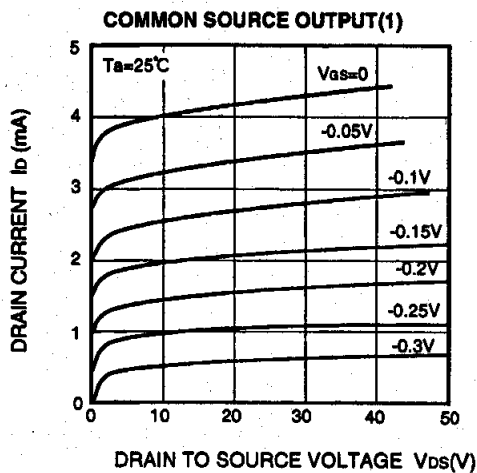
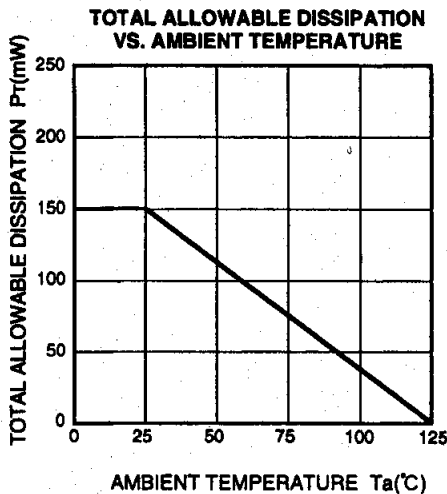
**ELECTRICAL CHARACTERISTICS (Ta=25°C)**

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
I <sub>SS</sub>	Gate leakage current	V <sub>GS</sub> =-30V,V <sub>DS</sub> =0			-1	nA
I <sub>DSS*</sub>	Drain current	V <sub>DS</sub> =10V,V <sub>GS</sub> =0	1	4	12	mA
V <sub>GS(off)</sub>	Cut off voltage	V <sub>DS</sub> =10V,I <sub>D</sub> =10 μA	-0.1		-2.0	V
y <sub>fs</sub>	Forward transfer admittance	V <sub>DS</sub> =10V,V <sub>GS</sub> =0,f=1kHz	6.0	15		mS
y <sub>fs</sub>	Forward transfer admittance	V <sub>DS</sub> =10V,I <sub>D</sub> =1mA,f=1kHz		8		mS
y <sub>os</sub>	Output admittance	V <sub>DS</sub> =10V,I <sub>D</sub> =1mA,f=1kHz		10		μS
C <sub>iss</sub>	Input capacitance	V <sub>DS</sub> =10V,V <sub>GS</sub> =0,f=1MHz		20		pF
NF	Noise figure	V <sub>DS</sub> =10V,I <sub>D</sub> =1mA,f=100Hz,R <sub>G</sub> =1kΩ		1.0		dB
R <sub>DS(ON)</sub>	Drain to source resistor	V <sub>DS</sub> =10mVrms(1kHz),V <sub>GS</sub> =0,I <sub>SS</sub> =5mA		70		Ω

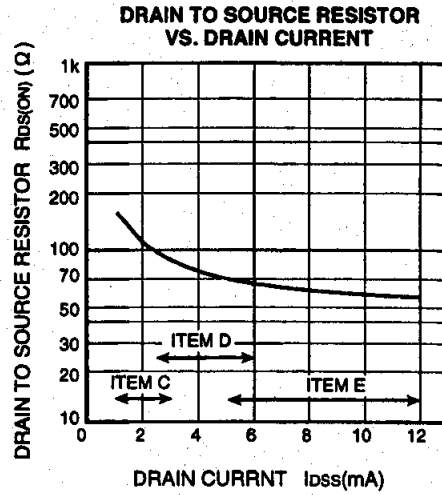
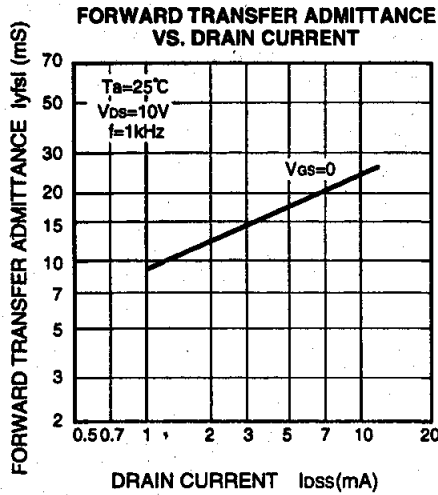
\* : It shows I<sub>SS</sub> classification in right table.

Item	C	D	E
I <sub>DSS</sub>	1.0 to 3.0	2.5 to 6.0	5.0 to 12

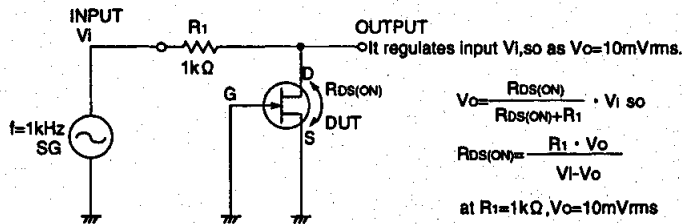
TYPICAL CHARACTERISTICS



**FOR LOW FREQUENCY AMPLIFY APPLICATION  
N CHANNEL JUNCTION TYPE**



**DRAIN TO SOURCE RESISTOR  $R_{DS(ON)}$  TEST CIRCUIT**



$$V_o = \frac{R_{DS(ON)}}{R_{DS(ON)} + R_1} \cdot V_i \text{ so}$$

$$R_{DS(ON)} = \frac{R_1 \cdot V_o}{V_i - V_o}$$

at  $R_1 = 1\text{k}\Omega, V_o = 10\text{mVrms}$

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 **ISAHAYA ELECTRONICS CORPORATION**

<http://www.idc-com.co.jp>  
6-41, TSUKUBA, ISAHAYA, NAGASAKI, 854-0065, JAPAN

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